

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC367AP,TC74HC367AF,TC74HC367AFN TC74HC368AP,TC74HC368AF,TC74HC368AFN

Hex Bus Buffer

TC74HC367AP/AF/AFN Non-Inverted
(3-state)

TC74HC368AP/AF/AFN Inverted (3-state)

The TC74HC367A and TC74HC368A are high speed CMOS 3-STATE BUS BUFFERS fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

They contain six buffers; four buffers are controlled by an enable input ($\overline{G1}$), and the other two buffers are controlled by another enable input ($\overline{G2}$). The outputs of each buffer group are enabled when $\overline{G1}$ and/or $\overline{G2}$ inputs are held low; if held high, these outputs are in a high impedance state.

The TC74HC367A is a non-inverting output type, while the TC74HC368A is an inverting output type.

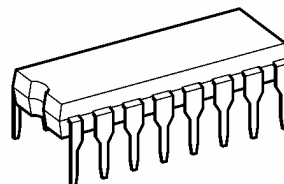
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 11 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu\text{A (max)}$ at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (min)}$
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 6 \text{ mA}$
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC} \text{ (opr)} = 2 \text{ to } 6 \text{ V}$
- Pin and function compatible with 74LS367/368

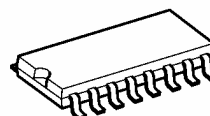
Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74HC367AP, TC74HC368AP



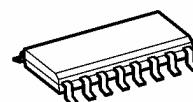
DIP16-P-300-2.54A

TC74HC367AF, TC74HC368AF



SOP16-P-300-1.27A

TC74HC367AFN, TC74HC368AFN



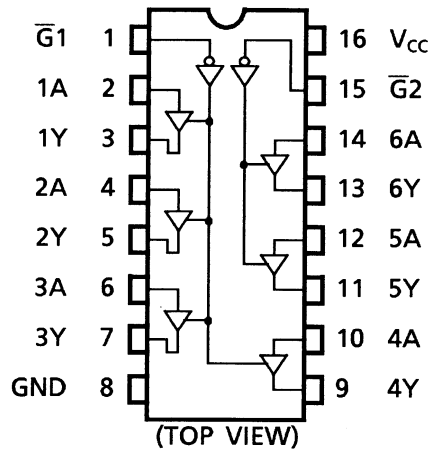
SOL16-P-150-1.27

Weight

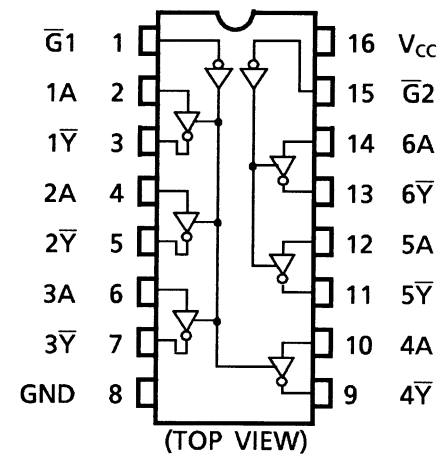
DIP16-P-300-2.54A	: 1.00 g (typ.)
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.13 g (typ.)

Pin Assignment

TC74HC367A



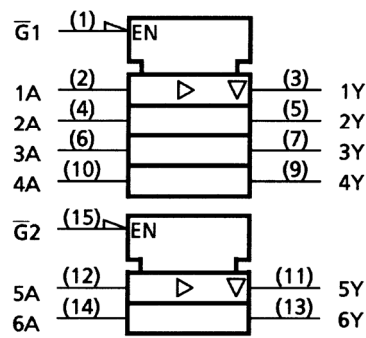
TC74HC368A



IEC Logic Symbol

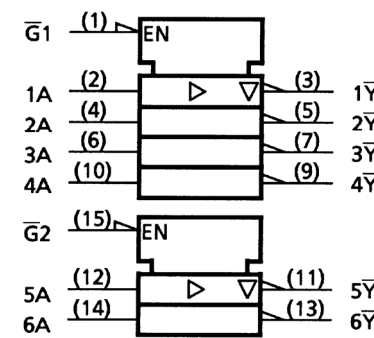
TC74HC367A

HEX BUS BUFFER
(3 - STATE)



TC74HC368A

HEX BUS BUFFER
(3 - STATE / INV.)



Truth Table

Inputs		Outputs	
\overline{G}	A_n	Y (367A)	\overline{Y} (368A)
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7	V
DC input voltage	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	± 20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 35	mA
DC V_{CC} /ground current	I_{CC}	± 75	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 2: 500 mW in the range of $T_a = -40$ to 65°C . From $T_a = 65$ to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 6	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	t_r, t_f	0 to 1000 ($V_{CC} = 2.0$ V) 0 to 500 ($V_{CC} = 4.5$ V) 0 to 400 ($V_{CC} = 6.0$ V)	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics
DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C				Ta = -40 to 85°C		Unit
				V _{CC} (V)	Min	Typ.	Max	Min	Max	
High-level input voltage	V _{IH}	—		2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	— — —	V
Low-level input voltage	V _{IL}	—		2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — —	0.50 1.35 1.80	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = -6 mA I _{OH} = -7.8 mA	6.0	5.9	6.0	—	5.9	—	
				4.5	4.18	4.31	—	4.13	—	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	6.0	5.68	5.80	—	5.63	—	V
				4.5	4.18	4.31	—	4.13	—	
			I _{OL} = 6 mA I _{OL} = 7.8 mA	6.0	5.68	5.80	—	5.63	—	
				4.5	4.18	4.31	—	4.13	—	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		6.0	—	—	±0.5	—	±5.0	μA
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	—	—	4.0	—	40.0	μA

AC Characteristics (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
			CL (pF)	VCC (V)	Min	Typ.	Max	Min	Max	
Output transition time	t_{TLH} t_{THL}	—	50	2.0	—	25	60	—	75	ns
				4.5	—	7	12	—	15	
				6.0	—	6	10	—	13	
Propagation delay time	t_{pLH} t_{pHL}	—	50	2.0	—	36	95	—	120	ns
				4.5	—	12	19	—	24	
				6.0	—	10	16	—	20	
			150	2.0	—	40	130	—	165	
				4.5	—	16	26	—	33	
				6.0	—	14	22	—	28	
Output enable time	t_{pZL} t_{pZH}	$R_L = 1 \text{ k}\Omega$	50	2.0	—	36	120	—	150	ns
				4.5	—	12	24	—	30	
				6.0	—	10	20	—	26	
			150	2.0	—	40	160	—	200	
				4.5	—	16	32	—	40	
				6.0	—	14	27	—	34	
Output disable time	t_{pLZ} t_{pHZ}	$R_L = 1 \text{ k}\Omega$	50	2.0	—	35	120	—	150	ns
				4.5	—	15	24	—	30	
				6.0	—	13	20	—	26	
Input capacitance	C_{IN}	—			—	5	10	—	10	pF
Output capacitance	C_{OUT}	—			—	10	—	—	—	pF
Power dissipation capacitance	C_{PD} (Note)	TC74HC367A			—	36	—	—	—	pF
		TC74HC368A			—	30	—	—	—	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

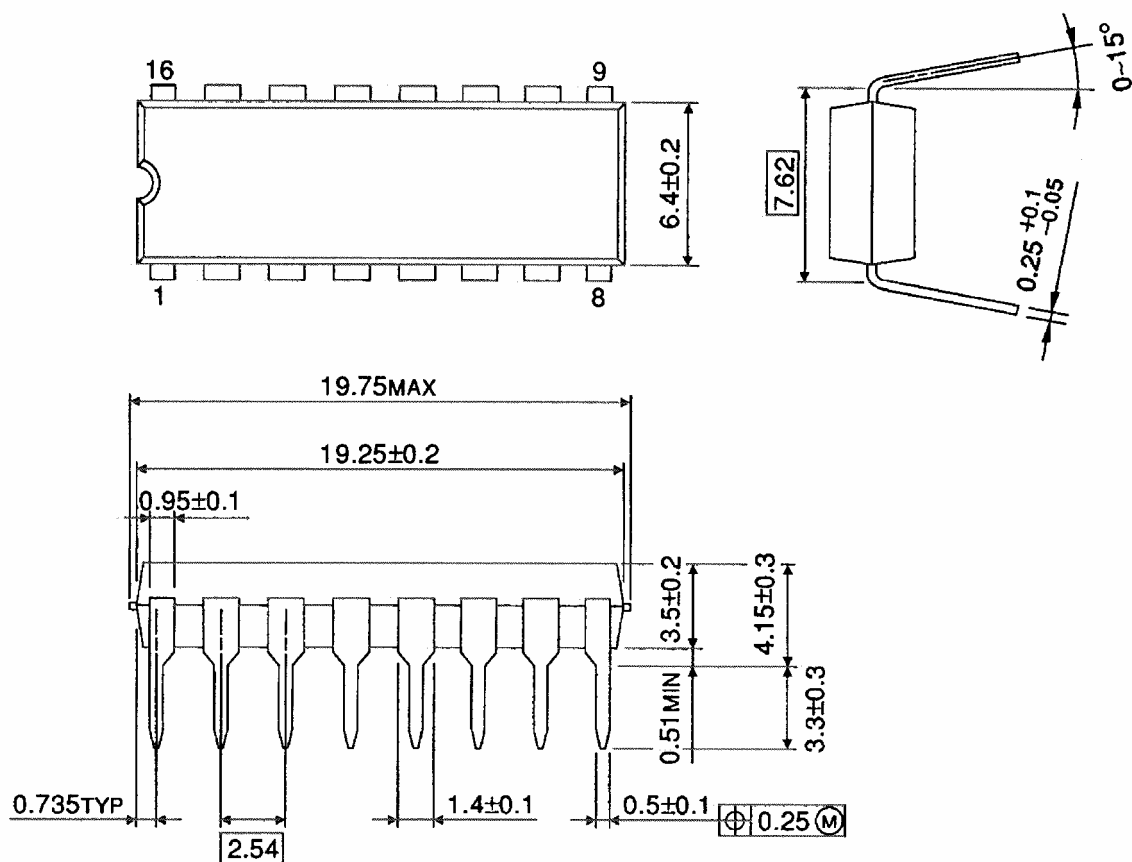
Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per bit)}$$

Package Dimensions

DIP16-P-300-2.54A

Unit : mm

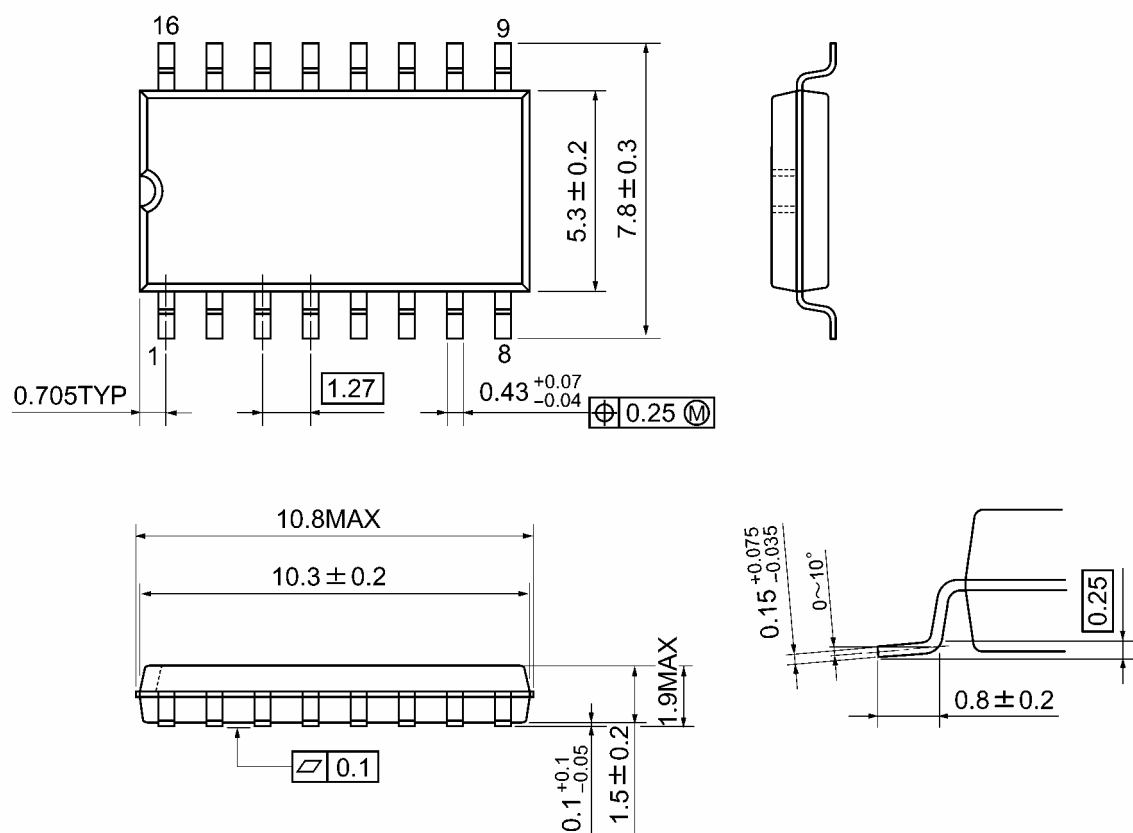


Weight: 1.00 g (typ.)

Package Dimensions

SOP16-P-300-1.27A

Unit: mm

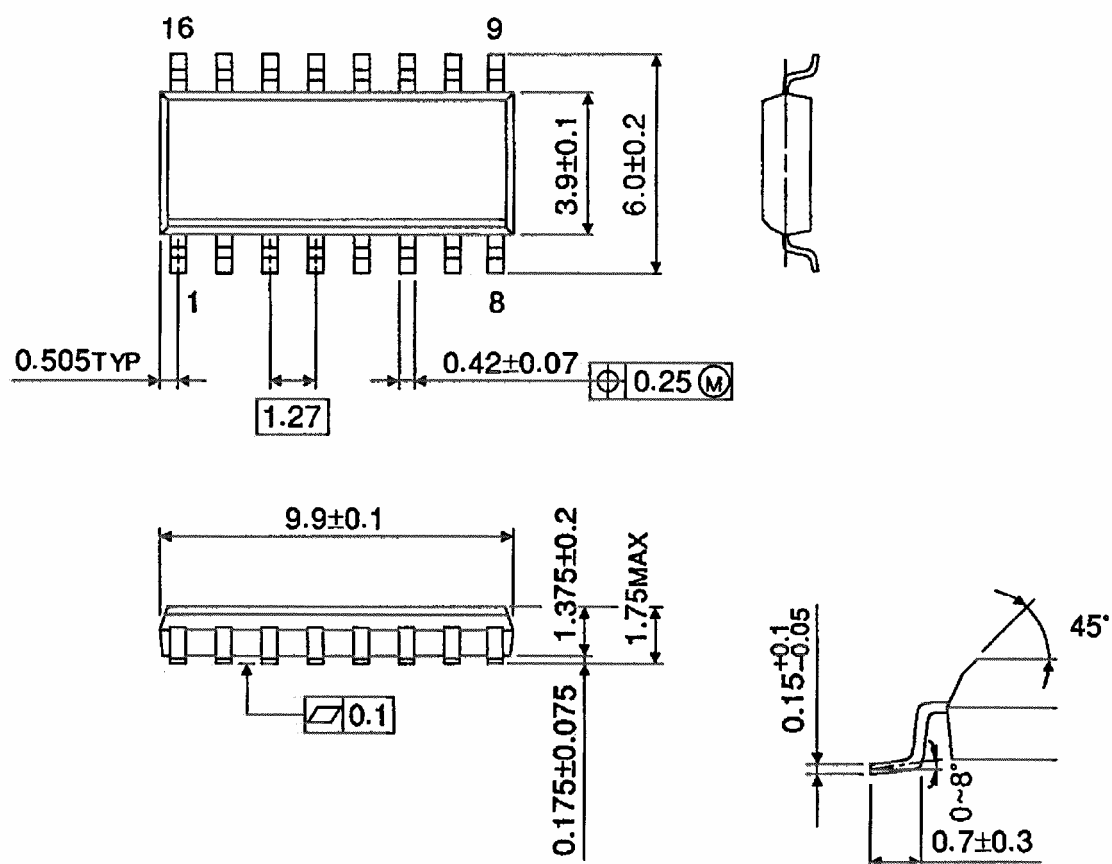


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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